

Radar Pulsed Power Transistor 150W, 1.2-1.4 GHz, 6ms Pulse, 25% Duty M/A-COM Products Released, 30 May 07

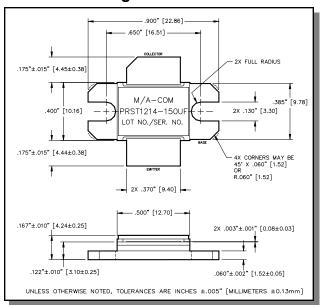
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- · Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- · RoHS compliant

#### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	70	V
Emitter-Base Voltage	$V_{EBO}$	4.0	V
Collector Current (Peak)	Ic	19.5	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	580	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

#### **Outline Drawing**



#### Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA		BV <sub>CES</sub>	70	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 40V		I <sub>CES</sub>	-	4.0	mA
Thermal Resistance	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	0.3	°C/W
Output Power	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	P <sub>OUT</sub>	150	-	W
Power Gain	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	G <sub>P</sub>	7.4	-	dB
Gain Flatness	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	ΔG	-	1.25	dB
Collector Efficiency	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	ης	45	-	%
Input Return Loss	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	RL	-	-9	dB
Pulse Droop	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	Droop	-	0.5	dB
Load Mismatch Tolerance	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 36V, Pin = 27W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

North America Tel: 800.366.2266 / Fax: 978.366.2266

<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macomtech.com for additional data sheets and product information.

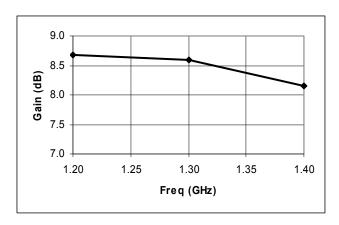


Radar Pulsed Power Transistor 150W, 1.2-1.4 GHz, 6ms Pulse, 25% Duty M/A-COM Products Released, 30 May 07

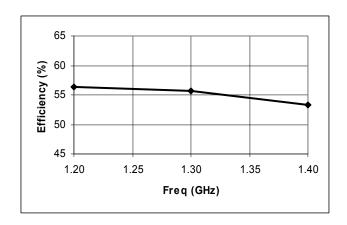
#### **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	Droop (dB)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	27	199	8.67	9.81	56.4	0.08	-11.3	S	Р
1.3	27	196	8.60	9.76	55.8	0.13	-18.8	S	Р
1.4	27	176	8.15	9.19	53.3	0.12	-16.0	S	Р

#### Gain vs. Frequency



#### Collector Efficiency vs. Frequency

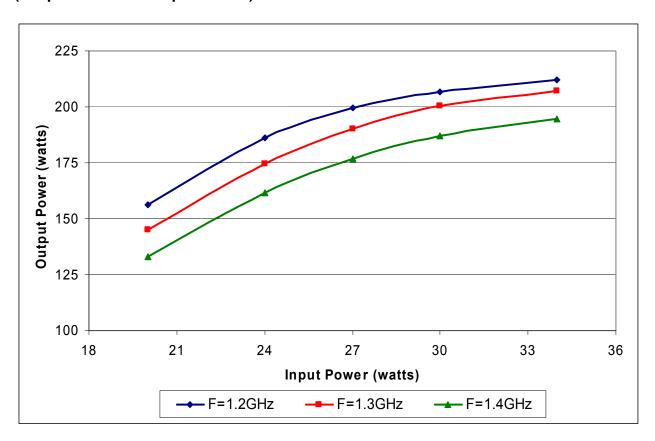


North America Tel: 800.366.2266 / Fax: 978.366.2266



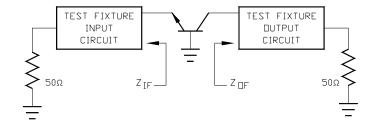
Radar Pulsed Power Transistor 150W, 1.2-1.4 GHz, 6ms Pulse, 25% Duty M/A-COM Products Released, 30 May 07

# RF Power Transfer Curve (Output Power Vs. Input Power)



#### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
1.2	1.7 - j1.8	2.0 - j2.3
1.3	1.6 - j1.3	1.95 - j2.0
1.4	1.4 - j1.0	1.8 - j1.85

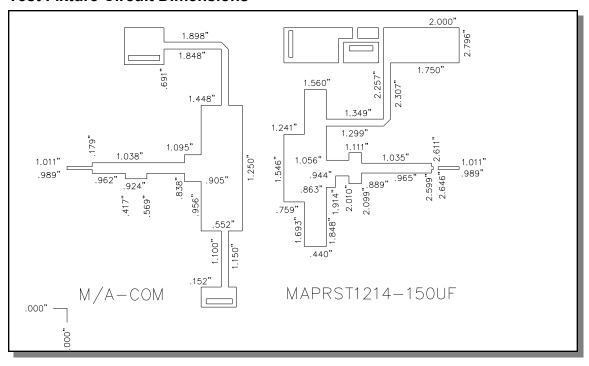


<sup>•</sup> Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

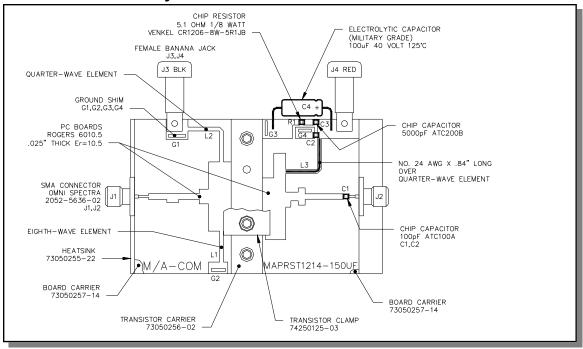


Radar Pulsed Power Transistor 150W, 1.2-1.4 GHz, 6ms Pulse, 25% Duty M/A-COM Products Released, 30 May 07

#### **Test Fixture Circuit Dimensions**



#### **Test Fixture Assembly**



PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
   Visit www.macomtech.com for additional data sheets and product information.

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Bipolar Transistors category:

Click to view products by MACOM manufacturer:

Other Similar products are found below:

MAPRST0912-50 MCH4016-TL-H MMBT5551-G MRF10120 15GN01CA-TB-E PH1214-25M MAPRST0912-350 MMBTH10-TP BFP 640F H6327 BFR 360F H6765 MRF10031 NSVF4009SG4T1G BFP 182R E7764 BFP405H6740XTSA1 MRF10350 ASMA201 BFR360FH6765XTSA1 BFP410H6327XTSA1 BFP620FH7764XTSA1 BFP720ESDH6327XTSA1 BFP720FH6327XTSA1 BFP720FH6327XTSA1 BFP720FH6327XTSA1 BFP720FH6327XTSA1 BFP720FH6327XTSA1 BFP720FH6327XTSA1 BFP720FH6327XTSA1 MMBT2222A-G BFP196WH6327XTSA1 BFP405FH6327XTSA1 BFP640ESDH6327XTSA1 BFR193L3E6327XTMA1 BFS483H6327XTSA1 NSVF4020SG4T1G NSVF6003SB6T1G MRF10005 BFP420FH6327XTSA1 BFP740FESDH6327XTSA1 BFR181E6327HTSA1 BFR181WH6327XTSA1 BFR182E6327HTSA1 BFR193E6327HTSA1 BFP181E7764HTSA1 BFP183WH6327XTSA1 BFP720H6327XTSA1 BFR182WH6327XTSA1 BFP180F764HTSA1 BFP183WH6327XTSA1 BFP720H6327XTSA1 BFR182WH6327XTSA1 BFV590GX MAPR-000912-500S00 BFR340FH6327XTSA1 STGWT30HP65FB